WESTCODE

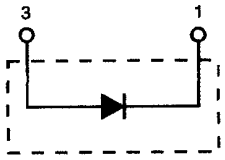
Fast Recovery Epitaxial Diode (FRED) Module

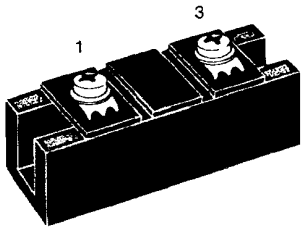
MEO 450-12 DA

V_{RRM} = 1200 V
I_{FAVM} = 453 A
t_{rr} = 450 ns

Preliminary data

V_{RSM} V	V_{RRM} V	Type
1200	1200	MEO 450-12DA





Symbol	Test Conditions		Maximum Ratings	
I_{FRMS}	T_C = 75°C		640	A
I_{FAVM} ①	T_C = 75°C; rectangular, d = 0.5		453	A
I_{FRM}	t_P < 10 µs; rep. rating, pulse width limited by T_{VJM}		2460	A
I_{FSM}	T_{VJ} = 45°C;	t = 10 ms (50 Hz), sine	4800	A
		t = 8.3 ms (60 Hz), sine	5280	A
	T_{VJ} = 150°C;	t = 10 ms (50 Hz), sine	4320	A
		t = 8.3 ms (60 Hz), sine	4750	A
I^2t	T_{VJ} = 45°C;	t = 10 ms (50 Hz), sine	115200	A^2s
		t = 8.3 ms (60 Hz), sine	117100	A^2s
	T_{VJ} = 150°C;	t = 10 ms (50 Hz), sine	93300	A^2s
		t = 8.3 ms (60 Hz), sine	94800	A^2s
T_{VJ}			-40...+150	°C
T_{stg}			-40...+125	°C
T_{Smax}			110	°C
P_{tot}	T_C = 25°C		1750	W
V_{ISOL}	50/60 Hz, RMS	t = 1 min	3000	V~
	I_{ISOL} ≤ 1 mA	t = 1 s	3600	V~
M_d	Mounting torque (M6)		2.25-2.75/20-25	Nm/lb.in.
	Terminal connection torque (M6)		4.50-5.50/40-48	Nm/lb.in.
d_S	Creeping distance on surface		12.7	mm
d_A	Strike distance through air		9.6	mm
a	Maximum allowable acceleration		50	m/s^2
Weight			150	g

Symbol	Test Conditions		Characteristic Values (per diode) typ.	max.	
I_R	T_{VJ} = 25°C	$V_R = V_{RRM}$		24	mA
	T_{VJ} = 25°C	$V_R = 0.8 \cdot V_{RRM}$		6	mA
	T_{VJ} = 125°C	$V_R = 0.8 \cdot V_{RRM}$		120	mA
V_F	I_F = 300 A;	T_{VJ} = 125°C		1.51	V
		T_{VJ} = 25°C		1.78	V
	I_F = 520 A;	T_{VJ} = 125°C		1.76	V
		T_{VJ} = 25°C		1.96	V
V_{T0}	For power-loss calculations only			1.16	V
r_T				1.15	mΩ
R_{thJS}	DC current			0.114	K/W
R_{thJC}	DC current			0.071	K/W
t_{rr}	I_F = 600 A	T_{VJ} = 100°C	450	500	ns
I_{RM}	V_R = 600 V	T_{VJ} = 25°C		110	A
	-di/dt = 800 A/µs	T_{VJ} = 100°C		165	A

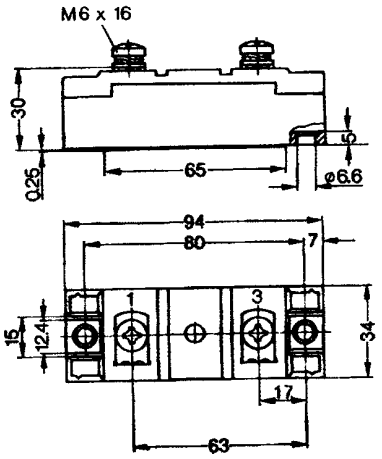
① I_{FAVM} rating includes reverse blocking losses at T_{VJM}, $V_R = 0.6\ V_{RRM}$, duty cycle d = 0.5
Data according to IEC 60747

Features
- International standard package with DCB ceramic base plate
- Planar passivated chips
- Short recovery time
- Low switching losses
- Soft recovery behaviour
- Isolation voltage 3600 V~
- UL registered E157027

Applications
- Antiparallel diode for high frequency switching devices
- Free wheeling diode in converters and motor control circuits
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Advantages
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses

Dimensions in mm (1 mm = 0.0394")



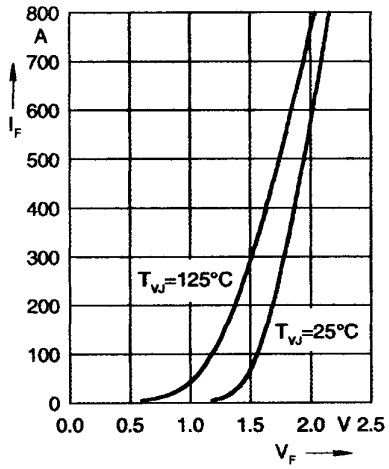


Fig. 1 Forward current I_F versus V_F

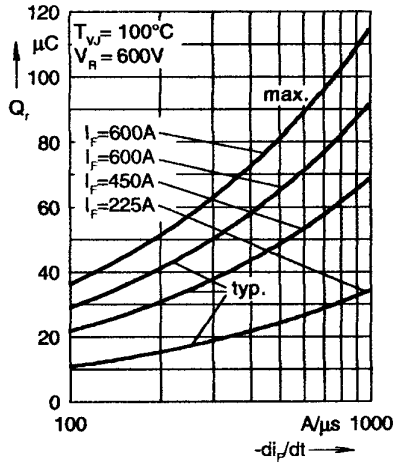


Fig. 2 Reverse recovery charge Q_r versus $-di_F$ / dt

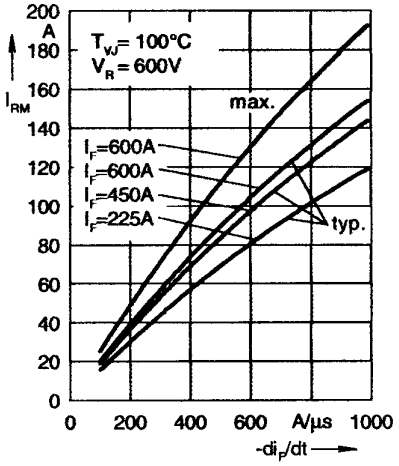


Fig. 3 Peak reverse current I_{RM} versus $-di_F$ / dt

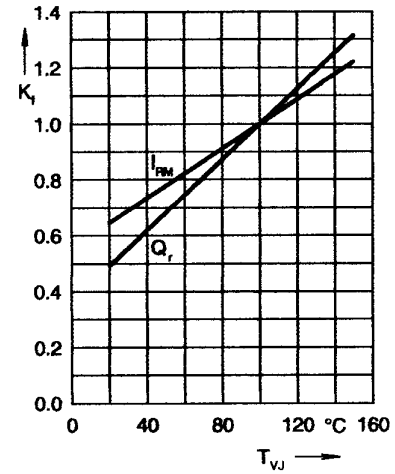


Fig. 4 Dynamic parameters Q_r, I_{RM} versus T_{VJ}

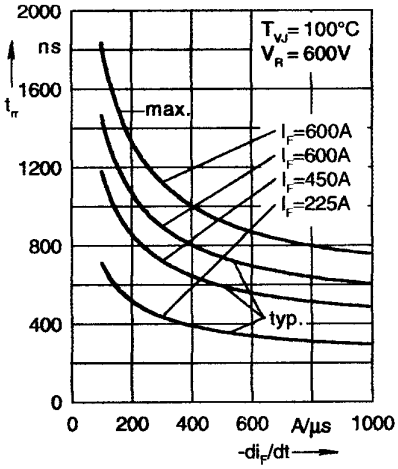


Fig. 5 Recovery time t_{rr} versus $-di_F$ / dt

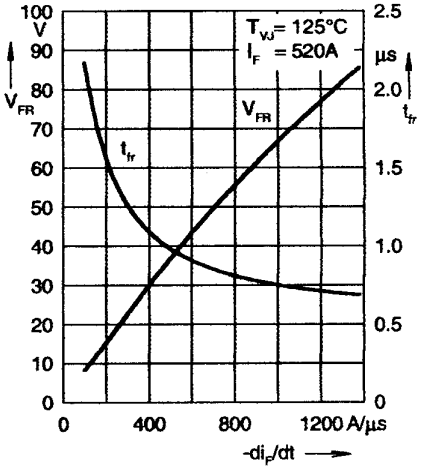


Fig. 6 Peak forward voltage V_{FR} and t_{fr} versus di_F / dt

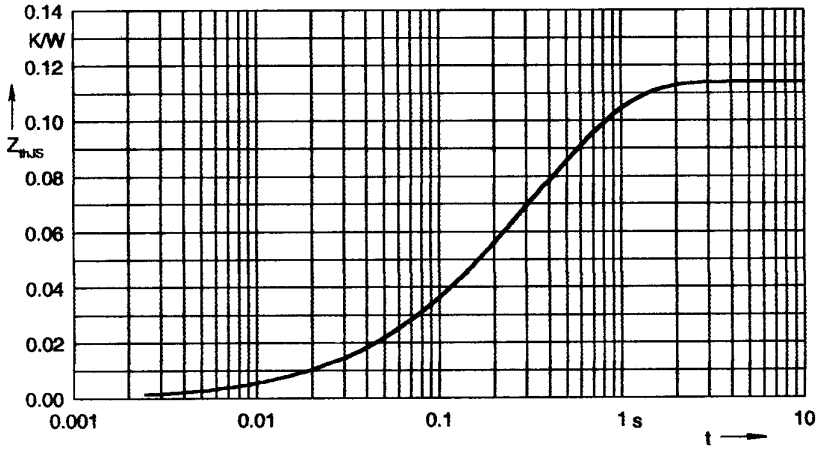


Fig. 7 Transient thermal impedance junction to case

Constants for Z_{thJS} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.001	0.08
2	0.004	0.024
3	0.027	0.112
4	0.082	0.464

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